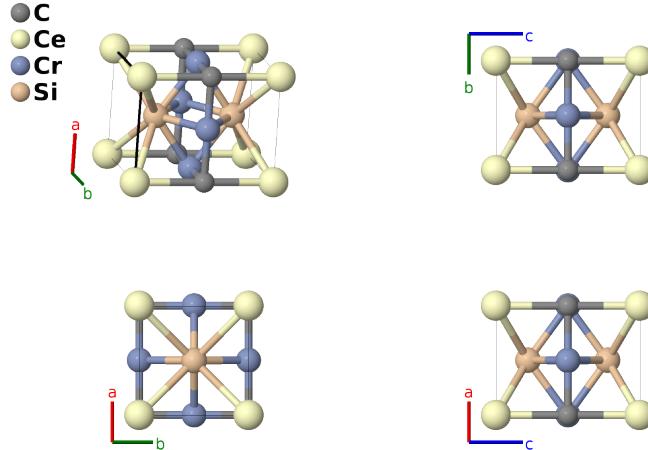


CeCr₂Si₂C Structure: ABC2D2_tP6_123_b_a_e_h-001

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<https://aflow.org/p/G8WV>

https://aflow.org/p/ABC2D2_tP6_123_b_a_e_h-001



Prototype	CCeCr ₂ Si ₂
AFLOW prototype label	ABC2D2_tP6_123_b_a_e_h-001
ICSD	90281
Pearson symbol	tP6
Space group number	123
Space group symbol	$P4/mmm$
AFLOW prototype command	aflow --proto=ABC2D2_tP6_123_b_a_e_h-001 --params=a, c/a, z ₄

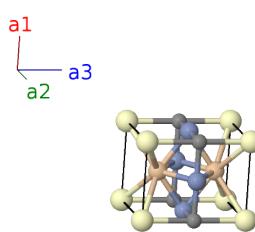
Other compounds with this structure

BaTi₂As₂O, BaTi₂Ti₂O, DyCr₂Si₂C, GdCr₂Si₂C, HoCr₂Si₂C, LaCr₂Si₂C, NdCr₂Si₂C, PrCr₂Si₂C, SmCr₂Si₂C, TbCr₂Si₂C, YCr₂Si₂C

- (Pohlkamp, 2001) refer to this as a “filled ThCr₂Si₂ structure.”

Simple Tetragonal primitive vectors

$$\begin{aligned}\mathbf{a}_1 &= a \hat{\mathbf{x}} \\ \mathbf{a}_2 &= a \hat{\mathbf{y}} \\ \mathbf{a}_3 &= c \hat{\mathbf{z}}\end{aligned}$$



Basis vectors

	Lattice coordinates		Cartesian coordinates	Wyckoff position	Atom type
\mathbf{B}_1	=	0	=	0	(1a)
\mathbf{B}_2	=	$\frac{1}{2}\mathbf{a}_3$	=	$\frac{1}{2}c\hat{\mathbf{z}}$	(1b)
\mathbf{B}_3	=	$\frac{1}{2}\mathbf{a}_2 + \frac{1}{2}\mathbf{a}_3$	=	$\frac{1}{2}a\hat{\mathbf{y}} + \frac{1}{2}c\hat{\mathbf{z}}$	(2e)
\mathbf{B}_4	=	$\frac{1}{2}\mathbf{a}_1 + \frac{1}{2}\mathbf{a}_3$	=	$\frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}c\hat{\mathbf{z}}$	(2e)
\mathbf{B}_5	=	$\frac{1}{2}\mathbf{a}_1 + \frac{1}{2}\mathbf{a}_2 + z_4\mathbf{a}_3$	=	$\frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}a\hat{\mathbf{y}} + cz_4\hat{\mathbf{z}}$	(2h)
\mathbf{B}_6	=	$\frac{1}{2}\mathbf{a}_1 + \frac{1}{2}\mathbf{a}_2 - z_4\mathbf{a}_3$	=	$\frac{1}{2}a\hat{\mathbf{x}} + \frac{1}{2}a\hat{\mathbf{y}} - cz_4\hat{\mathbf{z}}$	(2h)

References

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Found in

- [1] M. W. Pohlkamp and W. Jeitschko, *Preparation, Properties, and Crystal Structure of Quaternary Silicide Carbides RCr₂Si₂C (R = Y, La-Nd, Sm, Gd-Ho)*, Z. Naturforsch. B **56**, 1143–1148 (2001), doi:10.1515/znb-2001-1108.